

HA13168H

Multiple Voltage Regulator for Car Audio

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Description

The HA13168H is a compact multiple voltage regulator for car audio system. The outputs of this IC output consist of regulated 5.7 V output for a microcontroller, regulated 8 V output for CD driver, regulated 9.0 V output for audio control, and regulated 5 V output, VCC-dependent output for external output and VCC-dependent output for remote-ANT.

Functions

General

- ACC power monitor circuit is built-in as to detect low voltage.
- Low saturation output (PNP output) used for audio output.
- A reset signal output for a microcontroller.

Protections

- Output current limit circuit to avoid device destruction caused by shorted output, etc.
- High surge input protector against VCC and ACC.
- Built in a thermal shutdown circuit to prevent against the thermal destruction.

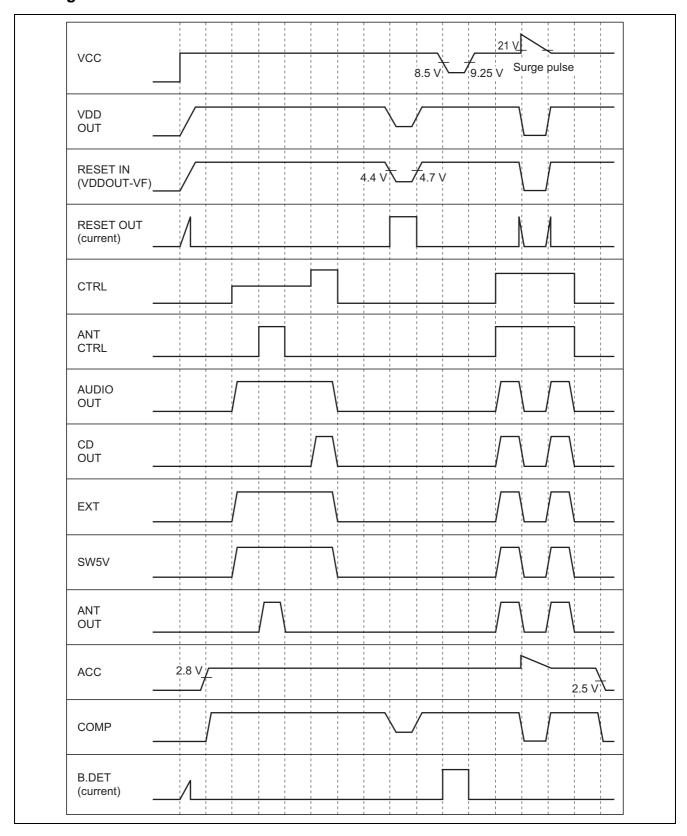
Pin Description and Equivalent Circuit

				Function		
Pin						Surge
No.	Pin Name	Specification	Equivalent Circuit	Normal Operation	TSD	Input
1	EXT OUT	VCC-1 V/300 mA min	Vcc Vcc	Output voltage is VCC-1 V when M or H level applied to CTRL pin.	0 V	0 V
2	ANT OUT	VCC-1 V/300 mA min	\$90 kΩ \$10 kΩ	Output voltage is VCC-1 V when M or H level to CTRL pin and H level to ANT-CTRL.	0 V	0 V
3	ACC IN		45 kΩ 	Connected to ACC.	_	_
4	VDD OUT	5.7 V/100 mA min	Vcc Vcc ₹215 kΩ ₹63 kΩ	Regular 5.7 V.	5.7 V	0 V
5	SW5V OUT	5.0 V/100 mA min	VDD	Output voltage is 5 V when M or H level applied to CTRL pin.	0 V	0 V
6	COMP OUT	5.0 V/100 mA min	\$50 kΩ	Output for ACC detector	0 V	0 V
7	ANT CTRL	_	51 kΩ 	L: ANT output OFF H: ANT output ON	_	_
8	VCC	_		Connected to VCC	_	_

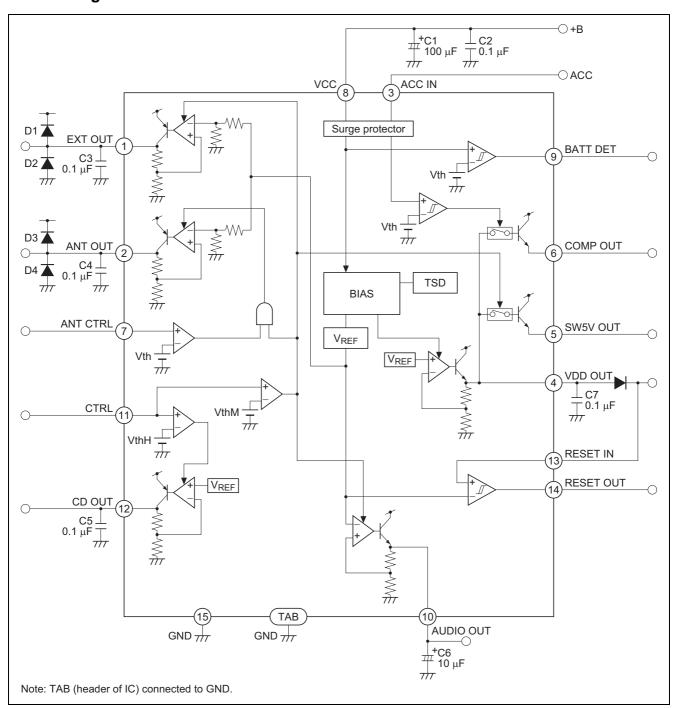
Pin Description and Equivalent Circuit (cont.)

				Function		
Pin No.	Pin Name	Specification	Equivalent Circuit	Normal Operation	TSD	Surge Input
9	BAT DET	_	VDD 250 kΩ 10 kΩ	Low battery detects. Active "L"	Detect	Not detect
10	AUDIO OUT	9.0 V/250 mA min	Vcc × 77.3 kΩ × 12.3 kΩ	Output voltage is 9 V when M or H level applied to CTRL pin.	0 V	0 V
11	CTRL		65 kΩ 35 kΩ	L: BIAS OFF M: BIAS ON H: CD ON		_
12	CD OUT	8.0 V/1.3 A min	Vcc	Output voltage is 8 V when H level applied to CTRL pin.	0 V	0 V
13	RESET IN	_	pin 13	Connected to power supply of microcontroller	_	_
14	RESET OUT	1 mA min	\$82 kΩ pin 14 \$33 kΩ m	A reset signal output: active "L"	Detect	
15	GND	_		Connected to GND	_	_

Timing Chart



Block Diagram



External Parts Lineup

Parts		Range of	Operation with Different Value from the Range of Recommended Value		
No.	Function	Recommended	More than the Range	Less than the Range	
C1	Bypass capacitor (Chemical capacitor)	Upper 100 μF	_	Unstable Lower ripple rejection ratio	
C2	To prevent oscillation For stability of IC, this capacitor is inserted near the power supply pin of the IC. We recommend Polyester film capacitor. *1	0.1 μF	Stability improve	Unstable	
C3 C4	To prevent oscillation *2	0.1 to 10000 μF	Unconfirmed	Unstable	
C5 C7	To prevent oscillation *2	0.1 to 470 μF	Unconfirmed	Unstable	
C6	To prevent oscillation	10 to 470 μF (ESR = 0.1 to 2 Ω)	Unconfirmed	Unstable	
D1, D2, D3, D4	Protection against mistake in joining. Terminal protection for short circuit to +B when VCC terminal is open and for short circuit to GND when GND terminal is open. We recommend Schottky barrier diodes.	IF≥1A	The ability to protect terminal improve.	The ability to protect terminal lower. And there is some possibility of destruction.	

Notes: 1. To improve stability, take notes of the below precautions.

- (1) Use capacitor that is temperature independent.
- (2) Use capacitor that is bias voltage independent.
- (3) No secondary resonance (non-inductive) capacitor.

And, pay attention to the following points so that there can be an efficient bypass of high frequency noise.

- (1) To eliminate PCB pattern inductance mount the capacitor as close as possible to the VCC and GND of IC.
- 2. For using of the lower limit of recommended value, take notes of the below precautions.
 - (1) Use capacitor that is temperature independent.
 - (2) Use capacitor that is bias voltage independent.
 - (3) No secondary resonance (non-inductive) capacitor.
- 3. To eliminate PCB pattern inductance mount the capacitor as close as possible to the VCC and GND of IC about C3, C4, C5, C6 and C7.

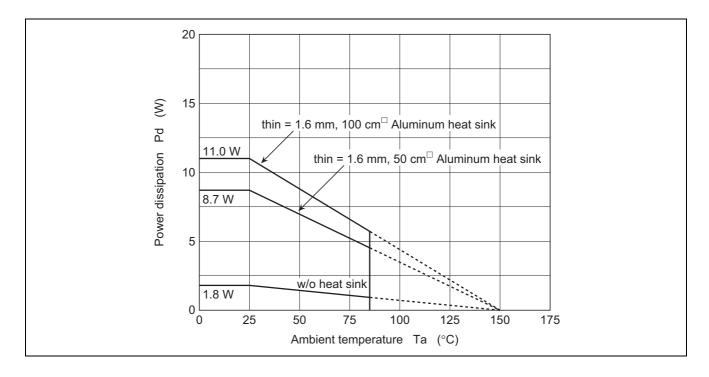
Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Rating	Unit	Note
Operating power supply voltage	Vcc	18	V	
DC supply voltage	Vcc(DC)	26	V	1
Peak voltage	Vcc(PEAK)	50	V	2
Power dissipation	Pd	36	W	3
Junction temperature	Tj	150	°C	
Operating temperature	Topr	-40 to +85	°C	
Storage temperature	Tstg	-55 to +125	°C	

Notes: Recommended power supply voltage range 10 to 16 V.

- 1. Applied time is less than 30 s.
- 2. Surge pulse as input.
- 3. Ta = 25°C.: Permissible power dissipation when using a heat sink of infinite area. Refer to the derating curves below.

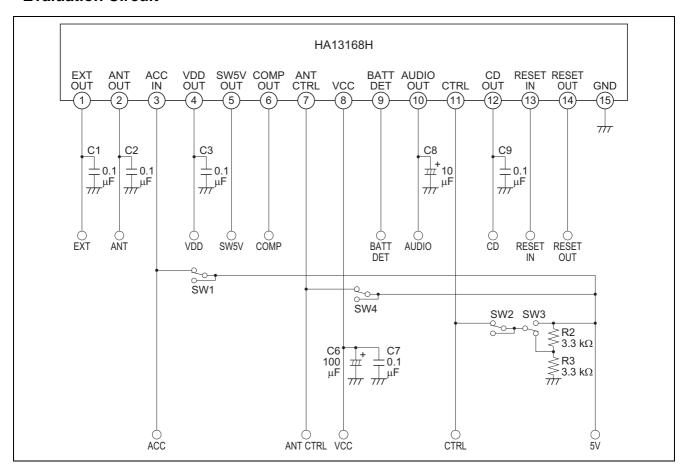


Electrical Characteristics

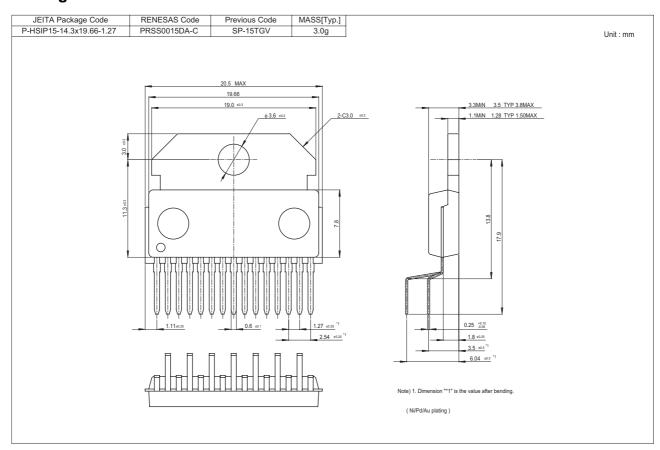
(unless otherwise noted, Vcc = 13.2 V, $Ta = 25^{\circ}\text{C}$)

Item		Symbol	Min	Тур	Max	Unit	Test Condition
Standby current		IST	_	460	700	μΑ	ACC = 0 V, CTRL = 0 V
CTRL L level (STBY mode)		VCL	0	_	1.0	V	
CTRL M level (CD OFF mode)		VCM	2.0	_	3.0	V	
CTRL H	level (CD ON mode)	VCH	4.0	_	_	V	
ANT CT	RL L level (ANT OFF mode)	VACL	0	_	2.0	V	
ANT CT	RL H level (ANT ON mode)	VACH	3.0	_	_	V	
VDD	Output voltage	Vo1	5.4	5.7	6.0	V	Io1 = 80 mA
OUT	Voltage regulation	ΔVo11		10	50	mV	Vcc = 10 to 16 V, lo1 = 80 mA
	Load regulation	ΔVo12		50	100	mV	Io1 = 0 to 80 mA
	Minimum I/O voltage differential	∆Vo13	1	1.0	1.5	V	lo1 = 80 mA
	Output current capacity	lo1	100	250	_	mA	Vo1 ≥ 5.4 V
	Ripple rejection ratio	SVR1	50	60	_	dB	f = 100 Hz, Io1 = 80 mA
CD	Output voltage	Vo2	7.6	8.0	8.4	V	lo2 = 1.0 A
OUT	Voltage regulation	∆Vo21	_	40	100	mV	Vcc = 10 to 16V, lo2 = 1.0 A
	Load regulation	ΔVo22	_	70	150	mV	lo2 = 10m to 1.0 A
	Minimum I/O voltage differential	ΔVo23		1.0	1.5	V	lo2 = 1.0 A
	Output current capacity	lo2	1.3	2.0	_	Α	Vo2 ≥ 7.6 V
	Ripple rejection ratio	SVR2	45	50	_	dB	f = 100 Hz, lo2 = 1.0 A
AUDIO	Output voltage	Vo3	8.5	9.0	9.5	V	Io3 = 160 mA
OUT	Voltage regulation	∆Vo31	_	30	90	mV	Vcc = 10 to 16 V, lo3 = 160 mA
	Load regulation	ΔVo32	_	100	200	mV	Io3 = 10 to 160 mA
	Minimum I/O voltage differential	∆Vo33	l	0.4	0.9	V	lo3 = 160 mA
	Output current capacity	lo3	250	350	_	mA	Vo3 ≥ 8.5 V
	Ripple rejection ratio	SVR3	40	50	_	dB	f = 100 Hz, Io3 = 160 mA
EXT	Differential I/O voltage	∆Vo41	_	1.0	1.5	V	Io4 = 300 mA
OUT	Load regulation	ΔV042	_	350	600	mV	Io4 = 10 to 300 mA
	Output current capacity	lo4	300	500	_	mA	Vo4 ≥ 11.7 V
ANT	Differential I/O voltage	∆Vo51	_	1.0	1.5	V	Io5 = 300 mA
OUT	Load regulation	ΔVo52	_	350	600	mV	lo5 = 10 to 300 mA
	Output current capacity	lo5	300	500	—	mA	Vo5 ≥ 11.7 V
SW5V	Output voltage	Vo6	4.6	5.0	5.4	V	lo6 = 80 mA, VDD = no load
OUT	Output current capacity	lo6	100	300	_	mA	Vo6 ≥ 4.6 V
ACC	Output voltage	Vo7	4.6	5.0	5.4	V	Io7 = 40 mA, VDD = no load
OUT	Output current capacity	lo7	100	300	_	mA	Vo7 ≥ 4.6 V
	Rise threshold voltage	VTHH7	2.6	2.8	3.0	V	
	Hysteresis range	ΔVTH7	0.2	0.3	0.4	V	
BATT.	Threshold voltage	VTHH8	8.1	8.5	8.9	V	
DET	Hysteresis range	ΔVTH8	0.55	0.75	0.95	V	
	Output current capacity	lo8	200	_	_	μΑ	Vo = 0.3 V
RESET	Threshold voltage	VTHH9	4.2	4.4	4.6	V	
	Hysteresis range	ΔVTH9	0.15	0.3	0.45	V	
	Output current capacity	lo9	1.0	2.5	_	mA	Vo = 0.5 V
	Reset circuit current	Icc9	_	100	180	μА	Reset in = 5.0 V

Evaluation Circuit



Package Dimensions



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